

CEN-U10
NPN SILICON
POWER TRANSISTOR



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CEN-U10 type is an NPN silicon power transistor designed for high voltage amplifier applications. This device is an electrical equivalent to Motorola's MPSU10.



TO-202 CASE

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	300	V
Collector-Emitter Voltage	V_{CEO}	300	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Continuous Collector Current	I_C	0.5	A
Power Dissipation	P_D	1.75	W
Power Dissipation ($T_C=25^\circ\text{C}$)	P_D	10	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Thermal Resistance	θ_{JA}	70	$^\circ\text{C/W}$
Thermal Resistance	θ_{JC}	12.5	$^\circ\text{C/W}$

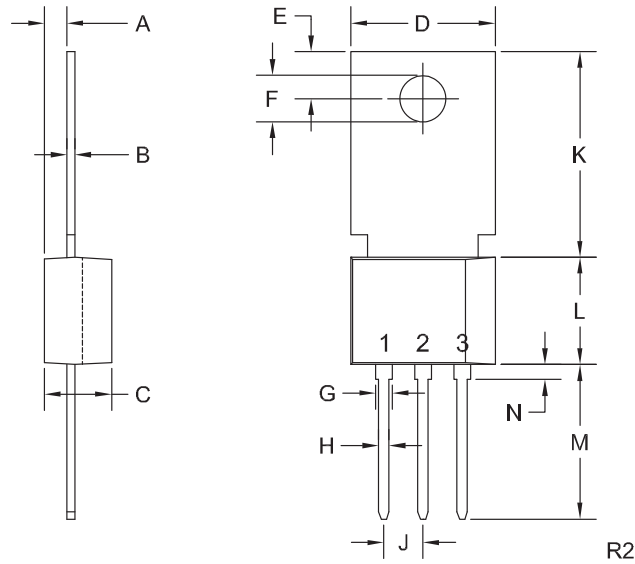
ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=200\text{V}$		200	nA
I_{EBO}	$V_{EB}=6.0\text{V}$		100	nA
BV_{CBO}	$I_C=100\mu\text{A}$	300		V
BV_{CEO}	$I_C=1.0\text{mA}$	300		V
BV_{EBO}	$I_E=100\mu\text{A}$	6.0		V
$V_{CE(SAT)}$	$I_C=20\text{mA}, I_B=2.0\text{mA}$		1.5	V
$V_{BE(SAT)}$	$I_C=20\text{mA}, I_B=2.0\text{mA}$		0.8	V
h_{FE}	$V_{CE}=10\text{V}, I_C=1.0\text{mA}$	25		
h_{FE}	$V_{CE}=10\text{V}, I_C=10\text{mA}$	40		
h_{FE}	$V_{CE}=10\text{V}, I_C=30\text{mA}$	40		
f_T	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	45		MHz
C_{ob}	$V_{CB}=20\text{V}, I_E=0, f=1.0\text{MHz}$		3.0	pF

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TO-202 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector
- Tab is common to pin 3

MARKING:

FULL PART NUMBER

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.071	1.40	1.80
B	0.016	0.024	0.40	0.60
C	0.173	0.181	4.40	4.60
D	0.374	0.413	9.50	10.5
E	0.118	0.154	3.00	3.90
F (DIA)	0.124	0.150	3.15	3.80
G	0.035	0.055	0.90	1.40
H	0.023	0.031	0.59	0.80
J	0.094	0.106	2.39	2.69
K	0.459	0.559	11.66	14.21
L	0.280	0.346	7.12	8.80
M	0.406	0.531	10.3	13.5
N	0.024	0.059	0.60	1.50

TO-202 (REV: R2)

R2 (23-January 2012)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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